

AP3216F3C

AP3216SF4C

### Features

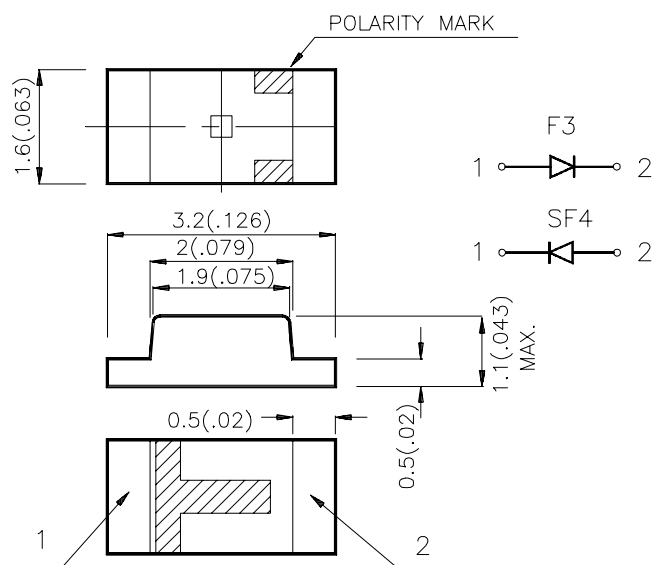
- WATER CLEAR LENS AVAILABLE.
- 3.2mmx1.6mm SMT LED, 1.1mm THICKNESS.
- HIGH POWER OUTPUT.
- PACKAGE: 2000PCS/REEL.

### Description

F3 Made with Gallium Arsenide Infrared Emitting diodes.

SF4 Made with Gallium Aluminum Arsenide Infrared  
Emitting diodes.

### Package Dimensions



#### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.2(0.0079)$  unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

## Selection Guide

| Part No.   | Dice   | Lens Type   | Po= (mW/sr)<br>@20mA |      | Viewing<br>Angle |
|------------|--------|-------------|----------------------|------|------------------|
|            |        |             | Min.                 | Typ. | 2θ1/2            |
| AP3216F3C  | GaAs   | WATER CLEAR | 0.5                  | 1.2  | 120°             |
| AP3216SF4C | GaAlAs | WATER CLEAR | 0.5                  | 1    | 120°             |

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

## Electrical / Optical Characteristics at T<sub>A</sub>=25°C

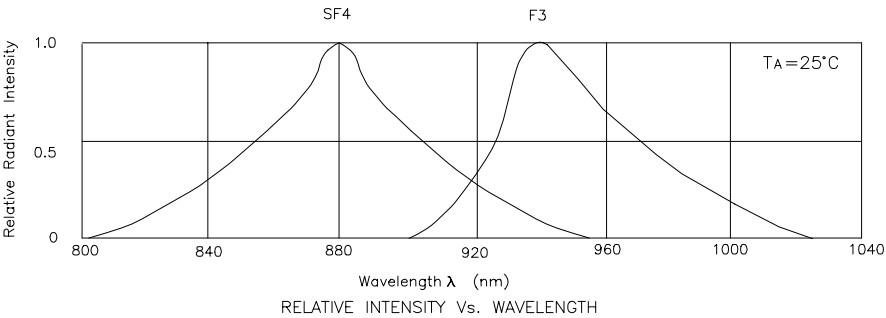
| Item                     | P/N       | Symbol         | Typ.       | Max.       | Unit | Condition  |
|--------------------------|-----------|----------------|------------|------------|------|------------|
| Forward Voltage          | F3<br>SF4 | V <sub>F</sub> | 1.2<br>1.3 | 1.5<br>1.7 | V    | IF=20mA    |
| Reverse Current          | F3<br>SF4 | I <sub>R</sub> | -          | 10<br>10   | uA   | VR=5V      |
| Junction Capacitance     | F3<br>SF4 | C              | 90<br>90   | -          | pF   | V=0 f=1MHz |
| Peak Spectral Wavelength | F3<br>SF4 | λ <sub>P</sub> | 940<br>880 | -          | nm   | IF=20mA    |
| Spectral Bandwidth       | F3<br>SF4 | Δλ             | 50<br>50   | -          | nm   | IF=20mA    |

## Absolute Maximum Ratings at T<sub>A</sub>=25°C

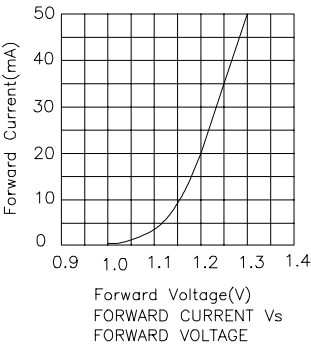
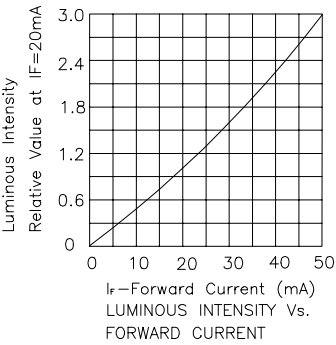
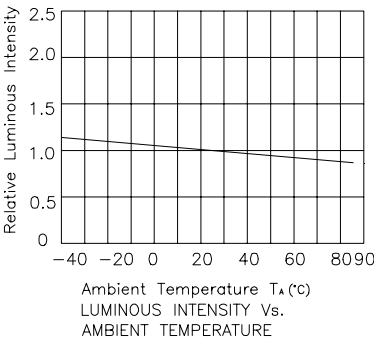
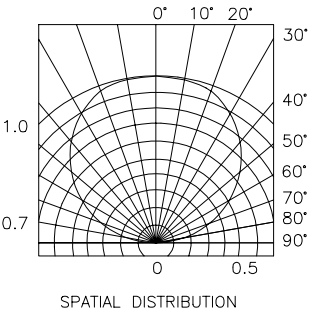
| Item                  | Symbol           | Maximum Rating | Units |
|-----------------------|------------------|----------------|-------|
| Power Dissipation     | P <sub>T</sub>   | 100            | mW    |
| Forward Current       | I <sub>F</sub>   | 50             | mA    |
| Peak Forward Current  | i <sub>FS</sub>  | 1.2            | A     |
| Reverse Voltage       | V <sub>R</sub>   | 5              | V     |
| Operating Temperature | T <sub>A</sub>   | -40~ +85       | °C    |
| Storage Temperature   | T <sub>STG</sub> | -40~ +85       | °C    |

Note:

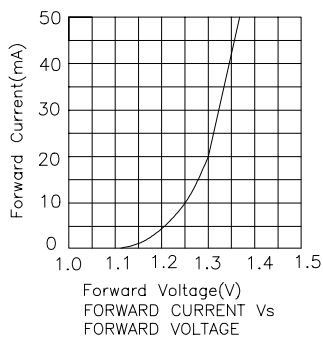
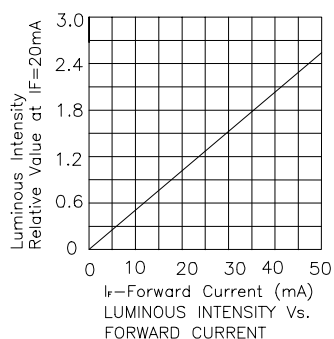
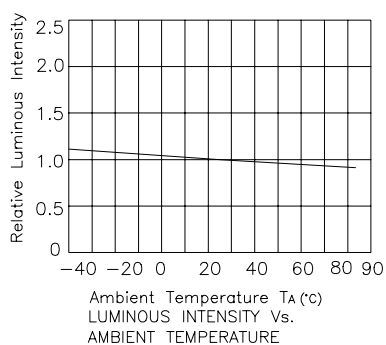
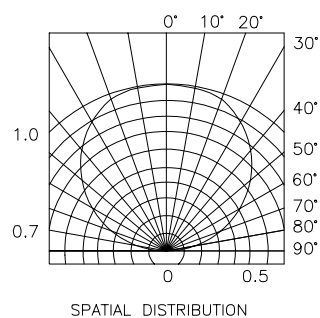
1.1/100 Duty Cycle, 10us Pluse Width.



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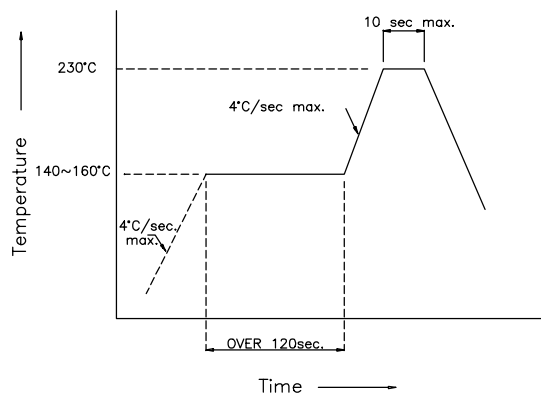


## AP3216SF4C

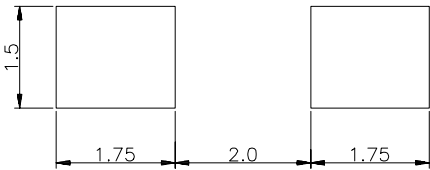


## AP3216F3C, AP3216SF4C SMT Reflow Soldering Instructions

Number of reflow process shall be less than 2 times and cooling process to normal temperature is required between first and second soldering process.



Recommended Soldering Pattern  
(Units : mm)



Tape Specifications  
(Units : mm)

